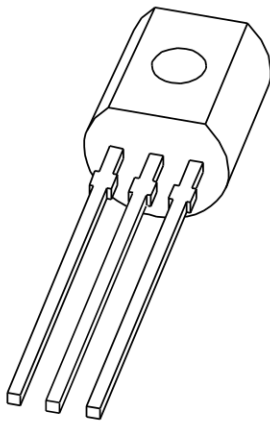


DATA SHEET



BC875; BC879 NPN Darlington transistors

Product specification
Supersedes data of 1997 Apr 22

1999 May 28

NPN Darlington transistors

BC875; BC879

FEATURES

- High DC current gain (min. 1 000)
- High current (max. 1 A)
- Low voltage (max. 80 V)
- Integrated diode and resistor.

APPLICATIONS

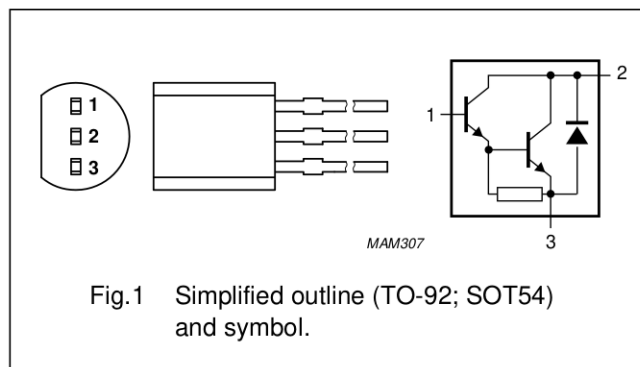
- Relay drivers.

DESCRIPTION

NPN Darlington transistor in a TO-92 (SOT54) plastic package. PNP complement: BC878.

PINNING

PIN	DESCRIPTION
1	base
2	collector
3	emitter



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{CBO}	collector-base voltage	open emitter			
	BC875		–	60	V
	BC879		–	100	V
V_{CES}	collector-emitter voltage	$V_{BE} = 0$			
	BC875		–	45	V
	BC879		–	80	V
V_{EBO}	emitter-base voltage	open collector	–	5	V
I_C	collector current (DC)		–	1	A
I_{CM}	peak collector current		–	2	A
I_B	base current (DC)		–	0.2	A
P_{tot}	total power dissipation	$T_{amb} \leq 25\text{ °C}$; note 1	–	0.83	W
T_{stg}	storage temperature		–65	+150	°C
T_j	junction temperature		–	150	°C
T_{amb}	operating ambient temperature		–65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

NPN Darlington transistors

BC875; BC879

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	150	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

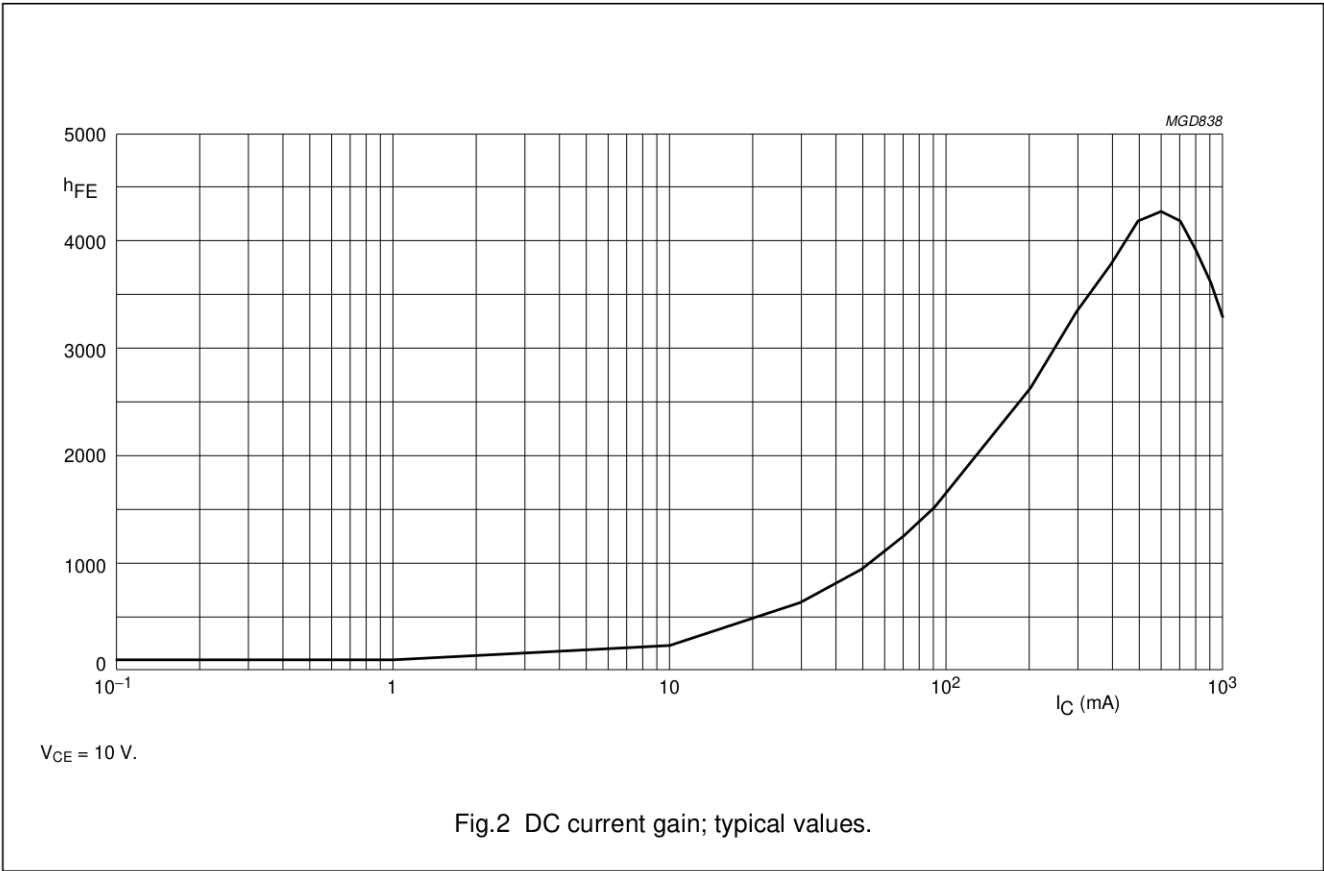
CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I_{CES}	collector cut-off current					
	BC875	$V_{BE} = 0; V_{CE} = 45\ \text{V}$	–	–	50	nA
	BC879	$V_{BE} = 0; V_{CE} = 80\ \text{V}$	–	–	50	nA
I_{EBO}	emitter cut-off current	$I_C = 0; V_{EB} = 4\ \text{V}$	–	–	50	nA
h_{FE}	DC current gain	$I_C = 150\ \text{mA}; V_{CE} = 10\ \text{V};$ see Fig.2	1000	–	–	
		$I_C = 0.5\ \text{A}; V_{CE} = 10\ \text{V};$ see Fig.2	2000	–	–	
V_{CEsat}	collector-emitter saturation voltage	$I_C = 0.5\ \text{A}; I_B = 0.5\ \text{mA}$	–	–	1.3	V
		$I_C = 1\ \text{A}; I_B = 1\ \text{mA}$	–	–	1.8	V
V_{BEsat}	base-emitter saturation voltage	$I_C = 1\ \text{A}; I_B = 1\ \text{mA}$	–	–	2.2	V
f_T	transition frequency	$I_C = 0.5\ \text{A}; V_{CE} = 5\ \text{V}; f = 100\ \text{MHz}$	–	200	–	MHz
Switching times (between 10% and 90% levels)						
t_{on}	turn-on time	$I_{Con} = 500\ \text{mA}; I_{Bon} = 0.5\ \text{mA};$ $I_{Boff} = -0.5\ \text{mA}$	–	500	–	ns
t_{off}	turn-off time		–	1300	–	ns

NPN Darlington transistors

BC875; BC879



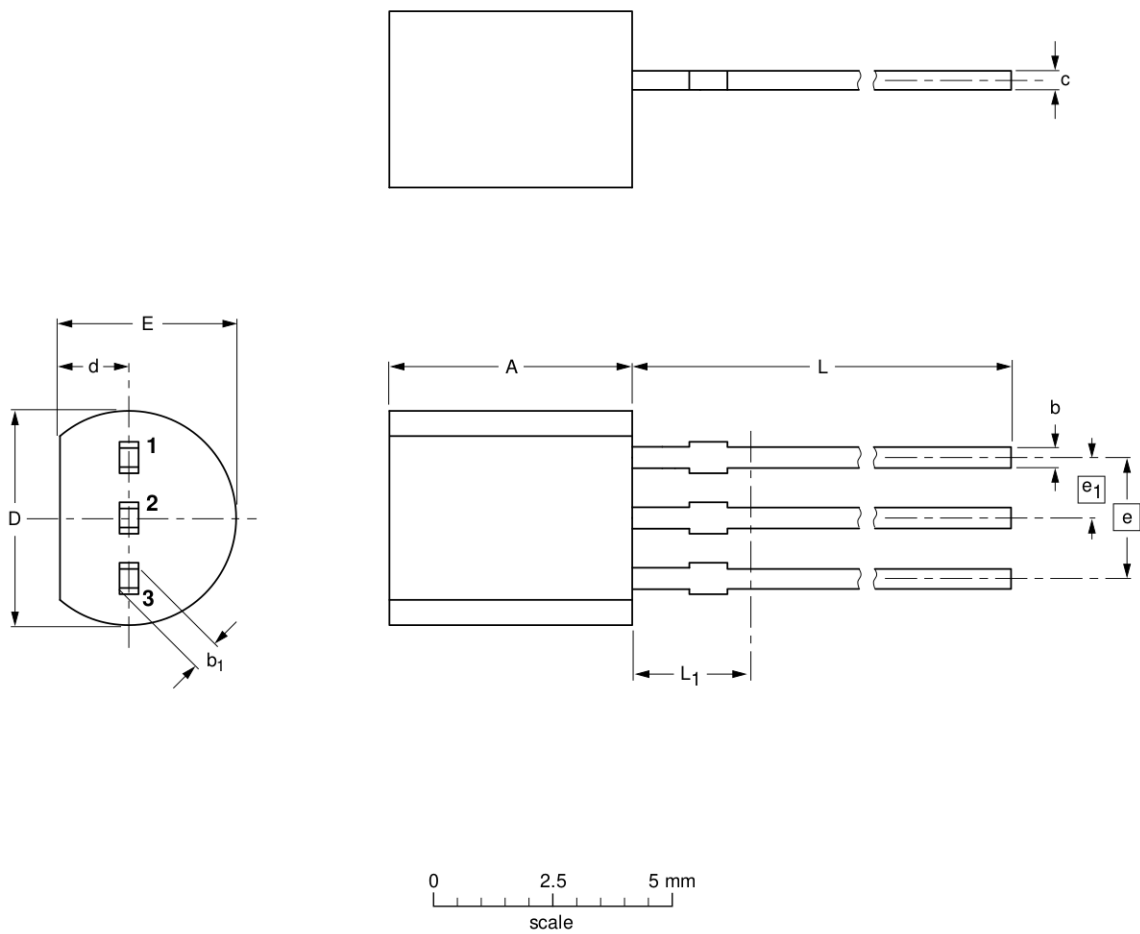
NPN Darlington transistors

BC875; BC879

PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b ₁	c	D	d	E	e	e ₁	L	L ₁ ⁽¹⁾
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT54		TO-92	SC-43			97-02-28

NPN Darlington transistorsBC875; BC879

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

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NPN Darlington transistors

BC875; BC879

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Printed in The Netherlands

115002/04/pp8

Date of release: 1999 May 28

Document order number: 9397 750 05409

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